General Description

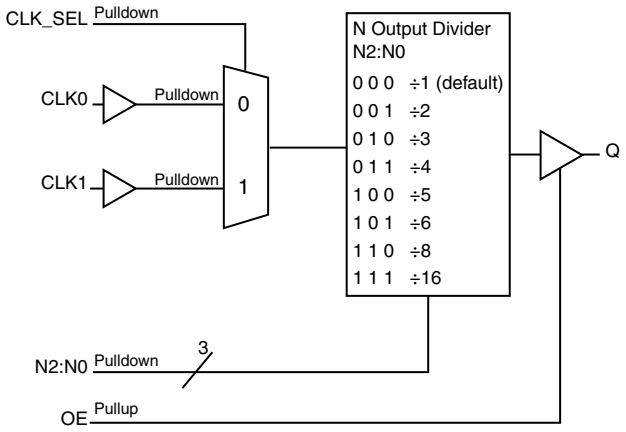
The ICS87001I-01 is a low skew, ÷1, ÷2, ÷3, ÷4, ÷5, ÷6, ÷8, ÷16 LVCMOS/LVTTL Clock Divider. The ICS87001I-01 has selectable clock inputs that accept single ended input levels. Output enable pin controls whether the output is in the active or high impedance state.

The ICS87001I-01 is characterized at 3.3V, 2.5V and mixed 3.3V/2.5V, 3.3V/1.8V, 2.5V/1.8V input/output supply operating modes.Guaranteed part-to-part skew characteristics make the ICS87001I-01 ideal for those applications demanding well defined performance and repeatability.

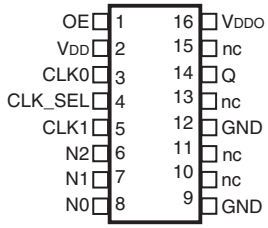
Features

- One LVCMOS / LVTTL output
- Selectable LVCMOS / LVTTL clock inputs
- Maximum output frequency: 250MHz
- Part-to-part skew: 135ps (typical)
- Power supply modes:
  Core/Output
  3.3V/3.3V
  3.3V/2.5V
  3.3V/1.8V
  2.5V/2.5V
  2.5V/1.8V
- -40°C to 85°C ambient operating temperature
- Available in lead-free (RoHS 6) package

Block Diagram



Pin Assignment



ICS87001I-01
16-Lead TSSOP
4.4mm x 5.0mm x 0.925mm
package body
G Package
Top View

Table 1. Pin Descriptions

Number	Name	Type		Description
1	OE	Input	Pullup	Output enable. When LOW, output is in HIGH impedance state. When HIGH, outputs are active. LVCMOS / LVTTL interface levels.
2	V_{DD}	Power		Power supply pin.
3, 5	CLK0, CLK1	Input	Pulldown	Single-ended clock inputs. LVCMOS/LVTTL interface levels.
4	CLK_SEL	Input	Pulldown	Input clock selection. When HIGH, selects CLK1 input. When LOW, selects CLK0 input. LVCMOS / LVTTL interface levels.
6, 7, 8	N2, N1, N0	Input	Pulldown	Output divider select pins. LVCMOS/LVTTL interface levels. See Table 3.
9, 12	GND	Power		Power supply ground.
10, 11, 13, 15	nc	Unused		No connect.
14	Q	Output		Single-ended clock output. LVCMOS/LVTTL interface levels.
16	V_{DDO}	Power		Output supply pin.

NOTE: *Pullup and Pulldown* refer to internal input resistors. See Table 2, *Pin Characteristics,* for typical values.

Table 2. Pin Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C_{IN}	Input Capacitance			4		pF
R_{PULLUP}	Input Pullup Resistor			51		kΩ
$R_{PULLDOWN}$	Input Pulldown Resistor			51		kΩ
C_{PD}	Power Dissipation Capacitance	V_{DDO} = 3.465V		6		pF
		V_{DDO} = 2.625V		5		pF
		V_{DDO} = 1.95V		5		pF
R_{OUT}	Output Impedance	V_{DDO} = 3.3V±5%		17		Ω
		V_{DDO} = 2.5V±5%		20		Ω
		V_{DDO} = 1.8V±0.15V		28		Ω

Function Table

Table 3. Programmable Output Divider Function Table

Inputs			N Divider Value	Maximum Output Frequency (MHz)
N2	N1	N0		
0	0	0	÷1 (default)	250
0	0	1	÷2	125
0	1	0	÷3	83.333
0	1	1	÷4	62.5
1	0	0	÷5	50
1	0	1	÷6	41.667
1	1	0	÷8	31.25
1	1	1	÷16	15.625

Absolute Maximum Ratings

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics or AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Item	Rating
Supply Voltage, V_{DD}	4.6V
Inputs, V_I	-0.5V to V_{DD} + 0.5V
Outputs, V_O	-0.5V to V_{DDO} + 0.5V
Package Thermal Impedance, θ_{JA}	100.3°C/W (0 mps)
Storage Temperature, T_{STG}	-65°C to 150°C

DC Electrical Characteristics

Table 4A. Power Supply DC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, T_A = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Power Supply Voltage		3.135	3.3	3.465	V
V_{DDO}	Output Supply Voltage		3.135	3.3	3.465	V
I_{DD}	Power Supply Current				55	mA
I_{DDO}	Output Supply Current	No Load			5	mA

Table 4B. Power Supply DC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 2.5V \pm 5\%$, T_A = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Power Supply Voltage		3.135	3.3	3.465	V
V_{DDO}	Output Supply Voltage		2.375	2.5	2.625	V
I_{DD}	Power Supply Current				55	mA
I_{DDO}	Output Supply Current	No Load			5	mA

Table 4C. Power Supply DC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 1.8V \pm 0.15V$, T_A = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Power Supply Voltage		3.135	3.3	3.465	V
V_{DDO}	Output Supply Voltage		1.65	1.8	1.95	V
I_{DD}	Power Supply Current				55	mA
I_{DDO}	Output Supply Current	No Load			5	mA

Table 4D. Power Supply DC Characteristics, $V_{DD} = V_{DDO} = 2.5V \pm 5\%$, T_A = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Positive Supply Voltage		2.375	2.5	2.625	V
V_{DDO}	Output Supply Voltage		2.375	2.5	2.625	V
I_{DD}	Power Supply Current				55	mA
I_{DDO}	Output Supply Current	No Load			5	mA

Table 4E. Power Supply DC Characteristics, V_{DD} = 2.5V ± 5%, V_{DDO} =1.8V ± 0.15V, T_A = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Positive Supply Voltage		2.375	2.5	2.625	V
V_{DDO}	Output Supply Voltage		1.65	1.8	1.95	V
I_{DD}	Power Supply Current				55	mA
I_{DDO}	Output Supply Current	No Load			5	mA

Table 4F. LVCMOS/LVTTL DC Characteristics, T_A = -40°C to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
V_{IH}	Input High Voltage		V_{DD} = 3.3V	2		V_{DD} + 0.3	V
			V_{DD} = 2.5V	1.7		V_{DD} + 0.3	V
V_{IL}	Input Low Voltage	CLK_SEL, CLK[0:1], N[2:0]	V_{DD} = 3.3V	-0.3		0.8	V
		OE	V_{DD} = 3.3V	-0.3		0.6	V
		CLK_SEL, CLK[0:1], N[2:0]	V_{DD} = 2.5V	-0.3		0.7	V
		OE	V_{DD} = 2.5V	-0.3		0.5	V
I_{IH}	Input High Current	CLK_SEL, CLK[0:1], N[2:0]	V_{DD} = V_{IN} = 3.465V or 2.625V			150	µA
		OE	V_{DD} = V_{IN} = 3.465V or 2.625V			5	µA
I_{IL}	Input Low Current	CLK_SEL, CLK[0:1], N[2:0]	V_{DD} = 3.465V or 2.625V, V_{IN} = 0V	-5			µA
		OE	V_{DD} = 3.465V or 2.625V, V_{IN} = 0V	-150			µA
V_{OH}	Output High Voltage; NOTE 1		V_{DDO} = 3.3V	2.6			V
			V_{DDO} = 2.5V	1.8			V
			V_{DDO} = 1.8V	1.25			V
V_{OL}	Output Low Voltage; NOTE 1		V_{DDO} = 3.3V			0.5	V
			V_{DDO} = 2.5V			0.5	V
			V_{DDO} = 1.8V			0.4	V
I_{OZL}	Output Hi-Z Current Low			-5			µA
I_{OZH}	Output Hi-Z Current High					5	µA

NOTE 1: Outputs terminated with 50Ω to V_{DDO}/2. See Parameter Measurement Information, *Output Load Test Circuit diagrams.*

AC Electrical Characteristics

Table 5A. AC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, T_A = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{OUT}	Output Frequency				250	MHz
t_{PD}	Propagation Delay, Low to High; NOTE 1	N ≤ 2	3.6	4.6	5.7	ns
		N > 2	4.3	5.5	6.7	ns
*t*sk(pp)	Part-to-Part Skew; NOTE 2, 3				750	ps
t_R / t_F	Output Rise/Fall Time	20% to 80%	0.4	0.6	1.0	ns
odc	Output Duty Cycle		40		60	%
t_{EN}	Output Enable Time				10	ns
t_{DIS}	Output Disable Time				10	ns

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.
All parameters measured at $f_{IN} \leq 250$MHz unless noted otherwise.
NOTE 1: Measured from the $V_{DD}/2$ of the input to $V_{DDO}/2$ of the output.
NOTE 2: Defined as skew between outputs on different devices operating at the same supply voltage, same frequency, same temperature and with equal load conditions. Using the same type of input on each device, the output is measured at $V_{DDO}/2$.
NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

Table 5B. AC Characteristics, $V_{DD} = 3.3V \pm 5\%$, $V_{DDO} = 2.5V \pm 5\%$, T_A = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{OUT}	Output Frequency				250	MHz
t_{PD}	Propagation Delay, Low to High; NOTE 1	N ≤ 2	3.5	4.8	6.2	ns
		N > 2	4.5	5.7	6.9	ns
*t*sk(pp)	Part-to-Part Skew; NOTE 2, 3				590	ps
t_R / t_F	Output Rise/Fall Time	20% to 80%	0.4	0.7	1.1	ns
odc	Output Duty Cycle		40		60	%
t_{EN}	Output Enable Time				10	ns
t_{DIS}	Output Disable Time				10	ns

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.
All parameters measured at $f_{IN} \leq 250$MHz unless noted otherwise.
NOTE 1: Measured from the $V_{DD}/2$ of the input to $V_{DDO}/2$ of the output.
NOTE 2: Defined as skew between outputs on different devices operating at the same supply voltage, same frequency, same temperature and with equal load conditions. Using the same type of input on each device, the output is measured at $V_{DDO}/2$.
NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

Table 5C. AC Characteristics, V_{DD} = 3.3V ± 5%, V_{DDO} = 1.8V ± 0.15V, T_A = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{OUT}	Output Frequency				250	MHz
t_{PD}	Propagation Delay, Low to High; NOTE 1	N ≤ 2	3.6	5.2	7.0	ns
		N > 2	4.8	6.2	7.6	ns
*t*sk(pp)	Part-to-Part Skew; NOTE 2, 3				680	ps
t_R / t_F	Output Rise/Fall Time	20% to 80%	0.4	1.0	2.3	ns
odc	Output Duty Cycle		40		60	%
t_{EN}	Output Enable Time				10	ns
t_{DIS}	Output Disable Time				10	ns

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.
All parameters measured at $f_{IN} \leq$ 250MHz unless noted otherwise.
NOTE 1: Measured from the V_{DD}/2 of the input to V_{DDO}/2 of the output.
NOTE 2: Defined as skew between outputs on different devices operating at the same supply voltage, same frequency, same temperature and with equal load conditions. Using the same type of input on each device, the output is measured at V_{DDO}/2.
NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

Table 5D. AC Characteristics, V_{DD} = V_{DDO} = 2.5V ± 5%, T_A = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{OUT}	Output Frequency				250	MHz
t_{PD}	Propagation Delay, Low to High; NOTE 1	N ≤ 2	3.7	4.9	6.2	ns
		N > 2	4.5	5.8	7.1	ns
*t*sk(pp)	Part-to-Part Skew; NOTE 2, 3				570	ps
t_R / t_F	Output Rise/Fall Time	20% to 80%	0.4	0.7	1.2	ns
odc	Output Duty Cycle		40		60	%
t_{EN}	Output Enable Time				10	ns
t_{DIS}	Output Disable Time				10	ns

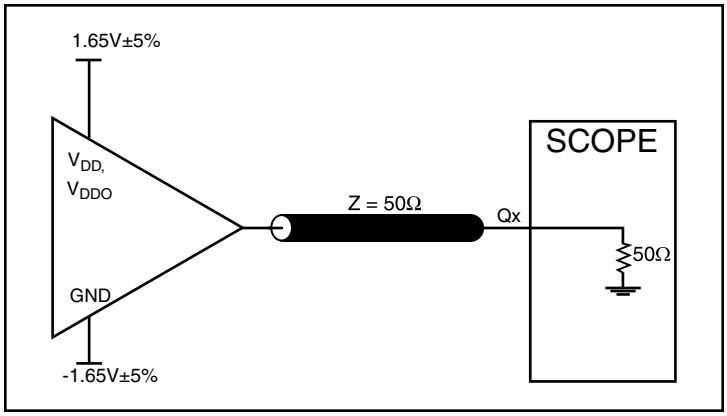
NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.
All parameters measured at $f_{IN} \leq$ 250MHz unless noted otherwise.
NOTE 1: Measured from the V_{DD}/2 of the input to V_{DDO}/2 of the output.
NOTE 2: Defined as skew between outputs on different devices operating at the same supply voltage, same frequency, same temperature and with equal load conditions. Using the same type of input on each device, the output is measured at V_{DDO}/2.
NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

Table 5E. AC Characteristics, V_{DD} = 2.5V ± 5%, V_{DDO} = 1.8V ± 0.15V, T_A = -40°C to 85°C

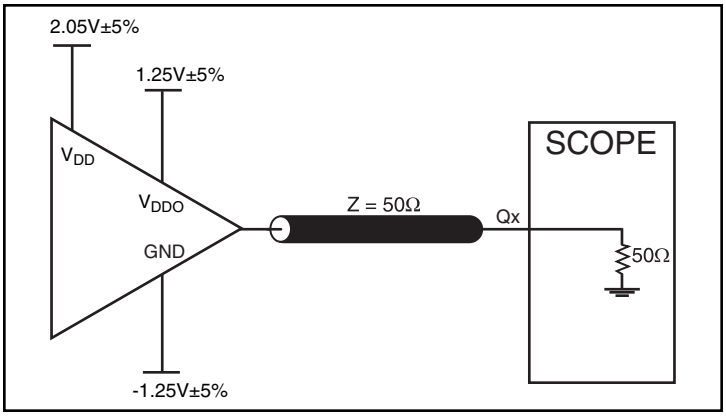
Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f_{OUT}	Output Frequency				250	MHz
t_{PD}	Propagation Delay, Low to High; NOTE 1	N ≤ 2	3.6	5.2	7.0	ns
		N > 2	4.8	6.2	7.7	ns
*t*sk(pp)	Part-to-Part Skew; NOTE 2, 3				550	ps
t_R / t_F	Output Rise/Fall Time	20% to 80%	0.5	1.1	2.5	ns
odc	Output Duty Cycle		40		60	%
t_{EN}	Output Enable Time				10	ns
t_{DIS}	Output Disable Time				10	ns

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. The device will meet specifications after thermal equilibrium has been reached under these conditions.
All parameters measured at $f_{IN} \leq$ 250MHz unless noted otherwise.
NOTE 1: Measured from the V_{DD}/2 of the input to V_{DDO}/2 of the output.
NOTE 2: Defined as skew between outputs on different devices operating at the same supply voltage, same frequency, same temperature and with equal load conditions. Using the same type of input on each device, the output is measured at V_{DDO}/2.
NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

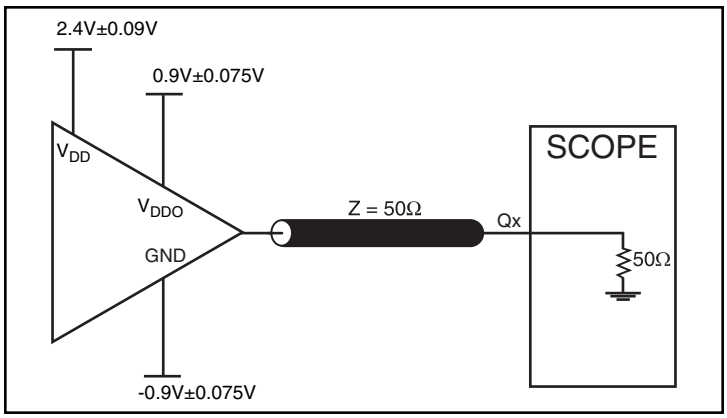
Parameter Measurement Information



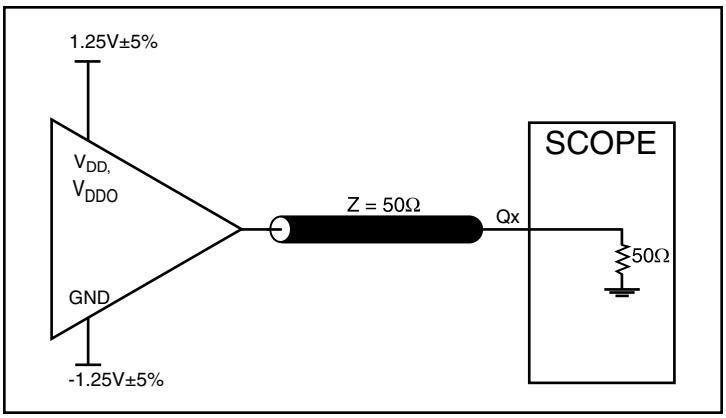
3.3V Core/3.3V LVCMOS Output Load AC Test Circuit



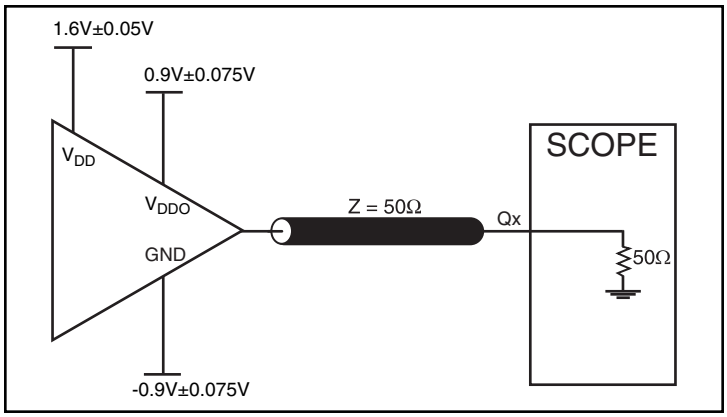
3.3V Core/2.5V LVCMOS Output Load AC Test Circuit



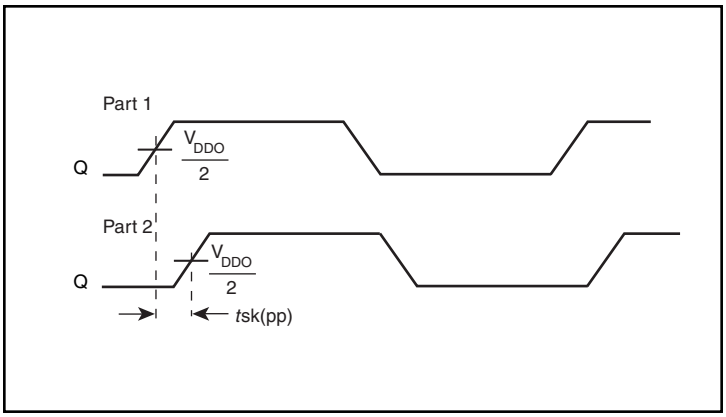
3.3V Core/1.8V LVCMOS Output Load AC Test Circuit



2.5V Core/2.5V LVCMOS Output Load AC Test Circuit

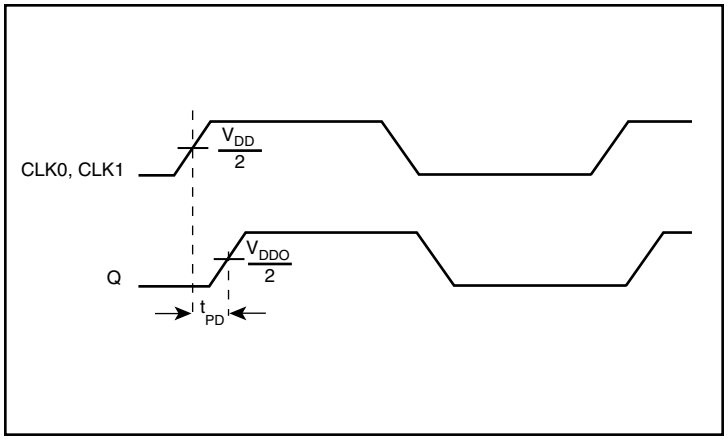


2.5V Core/1.8V LVCMOS Output Load AC Test Circuit

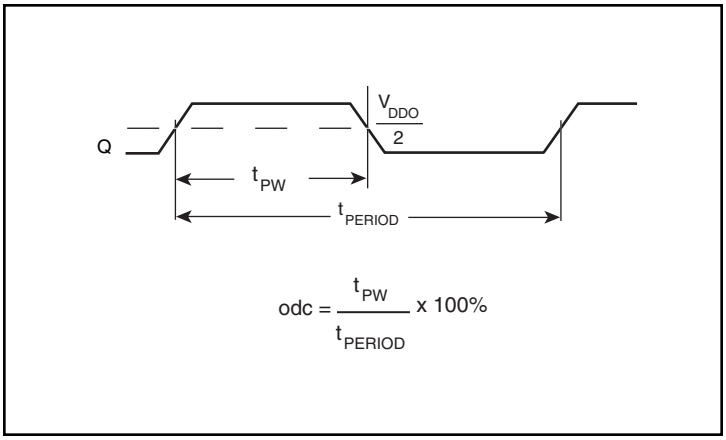


Part-to-Part Skew

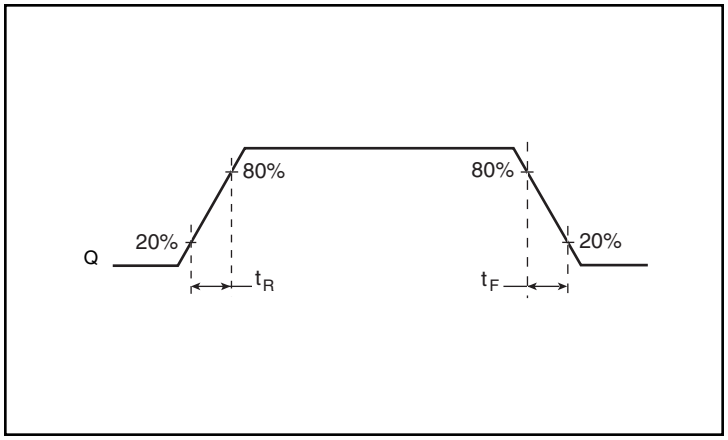
Parameter Measurement Information, continued



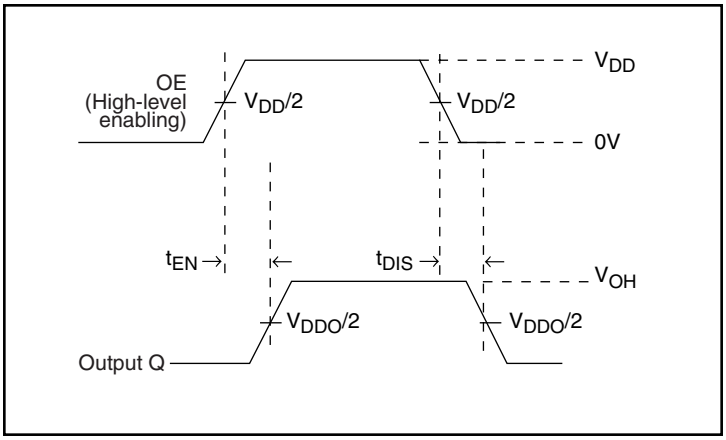
Propagation Delay



Output Duty Cycle/Pulse Width/Period



Output Rise/Fall Time



Output Enable/Disable Time

Applications Information

Recommendations for Unused Input Pins

Inputs:

CLK Inputs

For applications not requiring the use of a clock input, it can be left floating. Though not required, but for additional protection, a 1kΩ resistor can be tied from the CLK input to ground.

LVCMOS Control Pins

All control pins have internal pullups or pulldowns; additional resistance is not required but can be added for additional protection. A 1kΩ resistor can be used.

Power Considerations

This section provides information on power dissipation and junction temperature for the ICS87001I-01.
Equations and example calculations are also provided.

1. Power Dissipation.

The total power dissipation for the ICS87001I-01 is the sum of the core power plus the analog power plus the power dissipated in the load(s). The following is the power dissipation for V_{DD} = 3.3V + 5% = 3.465V, which gives worst case results.

- Power $(core)_{MAX} = V_{DD\_MAX} * I_{DD}$ = 3.465V * 55mA = **190.6mW**
- Power $(output)_{MAX} = V_{DDO\_MAX} * I_{DDO}$ = 3.465V * 5mA = 17.3mW

LVCMOS Output Power Dissipation

- Output Impedance R_{OUT} Power Dissipation due to Loading 50Ω to $V_{DD}/2$
  Output Current $I_{OUT} = V_{DD\_MAX} / [2 * (50\Omega + R_{OUT})]$ = 3.465V / [2 * (50Ω + 17Ω)] = **25.9mA**
- Power Dissipation on the R_{OUT} per LVCMOS output
  Power $(R_{OUT}) = R_{OUT} * (I_{OUT})^2$ = 17Ω * $(25.9mA)^2$ = **11.4mW**
- Total Power (R_{OUT}) = 11.4mW * 1 = **11.4mW**

Dynamic Power Dissipation at f_{OUT_MAX} (250MHz)

Power (250MHz) = C_{PD} * Frequency * $(V_{DDO})^2$ = 6pF * 250MHz * $(3.465V)^2$ = **18mW per output**

Total Power (250MHz) = 18mW * 1 = **18mW**

Total Power Dissipation

- **Total Power**
  = Power $(core)_{MAX}$ + Power $(output)_{MAX}$ + Total Power (R_{OUT}) + Total Power (250MHz)
  = 190.6mW + 17.3mW + 11.4mW + 18mW
  = 237.3mW

2. Junction Temperature.

Junction temperature, Tj, is the temperature at the junction of the bond wire and bond pad directly affects the reliability of the device. The maximum recommended junction temperature is 125°C. Limiting the internal transistor junction temperature, Tj, to 125°C ensures that the bond wire and bond pad temperature remains below 125°C.

The equation for Tj is as follows: $Tj = \theta_{JA} * Pd\_total + T_A$

Tj = Junction Temperature

θ_{JA} = Junction-to-Ambient Thermal Resistance

Pd_total = Total Device Power Dissipation (example calculation is in section 1 above)

T_A = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance θ_{JA} must be used. Assuming no air flow and a multi-layer board, the appropriate value is 100.3°C/W per Table 6 below.

Therefore, Tj for an ambient temperature of 85°C with all outputs switching is:

85°C + 0.237W * 100.3°C/W = 109°C. This is below the limit of 125°C.

This calculation is only an example. Tj will obviously vary depending on the number of loaded outputs, supply voltage, air flow and the type of board (multi-layer).

Table 6. Thermal Resistance θ_{JA} for 16 Lead TSSOP, Forced Convection

θ_{JA} by Velocity			
Meters per Second	**0**	**1**	**2.5**
Multi-Layer PCB, JEDEC Standard Test Boards	100.3°C/W	96.0°C/W	93.9°C/W

Reliability Information

Table 7. θ_{JA} vs. Air Flow Table for a 16 Lead TSSOP

θ_{JA} vs. Air Flow			
Meters per Second	**0**	**1**	**2.5**
Multi-Layer PCB, JEDEC Standard Test Boards	100.3°C/W	96.0°C/W	93.9°C/W

Transistor Count

The transistor count for ICS87001I-01: 2769

Package Outline and Package Dimensions

Package Outline - G Suffix for 16 Lead TSSOP

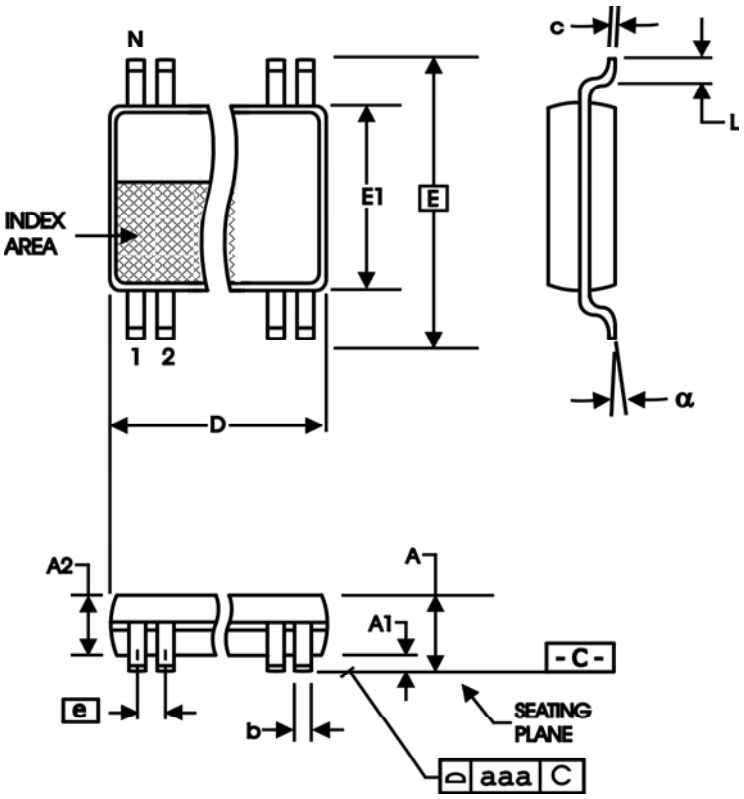


Table 8. Package Dimensions for 16 Lead TSSOP

All Dimensions in Millimeters		
Symbol	**Minimum**	**Maximum**
N	16	
A		1.20
A1	0.05	0.15
A2	0.80	1.05
b	0.19	0.30
c	0.09	0.20
D	4.90	5.10
E	6.40 Basic	
E1	4.30	4.50
e	0.65 Basic	
L	0.45	0.75
α	0°	8°
aaa		0.10

Reference Document: JEDEC Publication 95, MO-153

Ordering Information

Table 9. Ordering Information

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
87001BGI-01LF	001BI01L	“Lead-Free” 16 Lead TSSOP	Tube	-40°C to 85°C
87001BGI-01LFT	001BI01L	“Lead-Free” 16 Lead TSSOP	Tape & Reel	-40°C to 85°C

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LifeElectronics
Живое партнерство

ООО «ЛайфЭлектроникс» **“LifeElectronics” LLC**

ИНН 7805602321 КПП 780501001 Р/С 40702810122510004610 ФАКБ "АБСОЛЮТ БАНК" (ЗАО) в г.Санкт-Петербурге К/С 30101810900000000703 БИК 044030703

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- *Конкурентоспособные цены и скидки постоянным клиентам.*
- *Специальные условия для постоянных клиентов.*
- *Подбор аналогов.*
- *Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.*

- *Приемлемые сроки поставки, возможна ускоренная поставка.*
- *Доставку товара в любую точку России и стран СНГ.*
- *Комплексную поставку.*
- *Работу по проектам и поставку образцов.*
- *Формирование склада под заказчика.*

- *Сертификаты соответствия на поставляемую продукцию (по желанию клиента).*
- *Тестирование поставляемой продукции.*
- *Поставку компонентов, требующих военную и космическую приемку.*
- *Входной контроль качества.*
- *Наличие сертификата ISO.*

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- *Регистрацию проекта у производителя компонентов.*
- *Техническую поддержку проекта.*
- *Защиту от снятия компонента с производства.*
- *Оценку стоимости проекта по компонентам.*
- *Изготовление тестовой платы монтаж и пусконаладочные работы.*

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